

TOSHIBA**TC7SZ125F/FU**

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

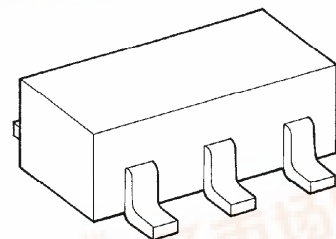
TC7SZ125F, TC7SZ125FU**BUS BUFFER****3-STATE OUTPUT****FEATURES**

- High Output Drive : ± 24 mA (Typ.)
($V_{CC} = 3$ V)
- Super High Speed Operation : $t_{PD} = 2.6$ ns (Typ.)
($V_{CC} = 5$ V, 50 pF)
- Operation Voltage Range : $V_{CC(opr)} = 1.8 \sim 5.5$ V
- Supply Voltage Data Retention : $V_{CC} = 1.5 \sim 5.5$ V
- 5 V Tolerant Function
- Matches the Performance of TC74LCX Series when Operated at 3.3 V V_{CC}

MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

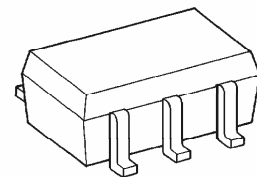
CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	V_{CC}	$-0.5 \sim 6$	V
DC Input Voltage	V_{IN}	$-0.5 \sim 6$	V
DC Output Voltage	V_{OUT}	$-0.5 \sim 6$	V
Input Diode Current	I_{IK}	± 20	mA
Output Diode Current	I_{OK}	± 20	mA
DC Output Current	I_{OUT}	± 50	mA
DC V_{CC} /Ground Current	I_{CC}	± 50	mA
Power Dissipation	P_D	200	mW
Storage Temperature	T_{stg}	$-65 \sim 150$	$^\circ\text{C}$
Lead Temperature (10 s)	T_L	260	$^\circ\text{C}$

TC7SZ125F



SSOP5-P-0.95

TC7SZ125FU



SSOP5-P-0.65A

WeightSSOP5-P-0.95 : 0.016 g (Typ.)
SSOP5-P-0.65A : 0.006 g (Typ.)

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DC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	TEST CONDITION		V _{CC} (V)	Ta = 25°C			Ta = -40~85°C		UNIT
					MIN.	TYP.	MAX.	MIN.	MAX.	
High-Level Input Voltage	V _{IH}			1.8	0.88 × V _{CC}	—	—	0.88 × V _{CC}	—	V
				2.3~ 5.5	0.75 × V _{CC}	—	—	0.75 × V _{CC}	—	
Low-Level Input Voltage	V _{IL}			1.8	—	—	0.12 × V _{CC}	—	0.12 × V _{CC}	V
				2.3~ 5.5	—	—	0.25 × V _{CC}	—	0.25 × V _{CC}	
High-Level Output Voltage	V _{OH}	V _{IN} = V _{IH}	I _{OH} = -100 μA	1.8	1.7	1.8	—	1.7	—	V
				2.3	2.2	2.3	—	2.2	—	
				3.0	2.9	3.0	—	2.9	—	
				4.5	4.4	4.5	—	4.4	—	
			I _{OH} = -8 mA	2.3	1.9	2.15	—	1.9	—	
			I _{OH} = -16 mA	3.0	2.4	2.8	—	2.4	—	
			I _{OH} = -24 mA	3.0	2.3	2.68	—	2.3	—	
			I _{OH} = -32 mA	4.5	3.8	4.2	—	3.8	—	
Low-Level Output Voltage	V _{OL}	V _{IN} = V _{IL}	I _{OL} = 100 μA	1.8	—	0	0.1	—	0.1	V
				2.3	—	0	0.1	—	0.1	
				3.0	—	0	0.1	—	0.1	
				4.5	—	0	0.1	—	0.1	
			I _{OL} = 8 mA	2.3	—	0.1	0.3	—	0.3	
			I _{OL} = 16 mA	3.0	—	0.15	0.4	—	0.4	
			I _{OL} = 24 mA	3.0	—	0.22	0.55	—	0.55	
			I _{OL} = 32 mA	4.5	—	0.22	0.55	—	0.55	
Input Leakage Current	I _{IN}	V _{IN} = 5.5 V or GND		0~ 5.5	—	—	± 1	—	± 10	μA
Power Off Leakage Current	I _{OFF}	V _{IN} or V _{OUT} = 5.5 V		0.0	—	—	1	—	10	μA
Quiescent Supply Current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	—	—	2	—	20	μA

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3$ ns)

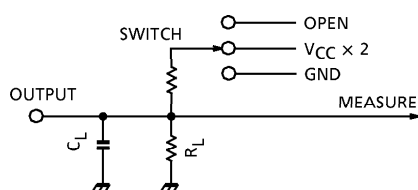
CHARACTERISTIC	SYMBOL	TEST CONDITION	Ta = 25°C				Ta = -40~85°C		UNIT
			V _{CC} (V)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time	t _{PLH} t _{PHL}	C _L = 15 pF, R _L = 1 MΩ (Figure 1)	1.8	2.0	5.3	11.0	2.0	11.5	ns
			2.5 ± 0.2	0.8	3.4	7.5	0.8	8.0	
			3.3 ± 0.3	0.5	2.5	5.2	0.5	5.5	
			5.0 ± 0.5	0.5	2.1	4.5	0.5	4.8	
		C _L = 50 pF, R _L = 500 Ω (Figure 1)	3.3 ± 0.3	1.5	3.2	5.7	1.5	6.0	
			5.0 ± 0.5	0.8	2.6	5.0	0.8	5.3	
Output Enable Time	t _{PZL} t _{PZH}	C _L = 50 pF, R _L = 500 Ω (Figure 1)	1.8	2.0	7.0	12.5	2.0	13.0	ns
			2.5 ± 0.2	1.5	4.6	8.5	1.5	9.0	
			3.3 ± 0.3	1.5	3.5	6.2	1.5	6.5	
			5.0 ± 0.5	0.8	2.8	5.5	0.8	5.8	
Output Disable Time	t _{PLZ} t _{PHZ}	C _L = 50 pF, R _L = 500 Ω (Figure 1)	1.8	2.0	5.4	11.0	2.0	12.0	ns
			2.5 ± 0.2	1.5	3.5	8.0	1.5	8.5	
			3.3 ± 0.3	1.0	2.8	5.7	1.0	6.0	
			5.0 ± 0.5	0.5	2.1	4.7	0.5	5.0	
Input Capacitance	C _{IN}		0~5.5	—	4	—	—	—	pF
Power Dissipation Capacitance	C _{PD}	(Note 1)	3.3	—	17	—	—	—	pF
			5.5	—	24	—	—	—	

(Note 1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation.

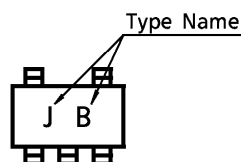
$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

Figure 1 AC Characteristics Measurement Circuit



CHARACTERISTICS	SWITCH
t _{PLH} , t _{PHL}	OPEN
t _{PLZ} , t _{PZL}	V _{CC} × 2
t _{PHZ} , t _{PZH}	GND

MARKING



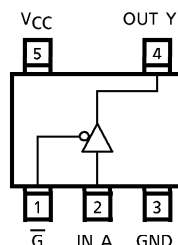
TRUTH TABLE

INPUT		OUTPUT
A	$\bar{G}$	Y
x	H	Z
L	L	L
H	L	H

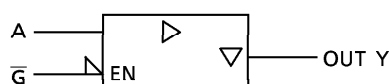
x : Don't Care

Z : High Impedance

PIN ASSIGNMENT (TOP VIEW)

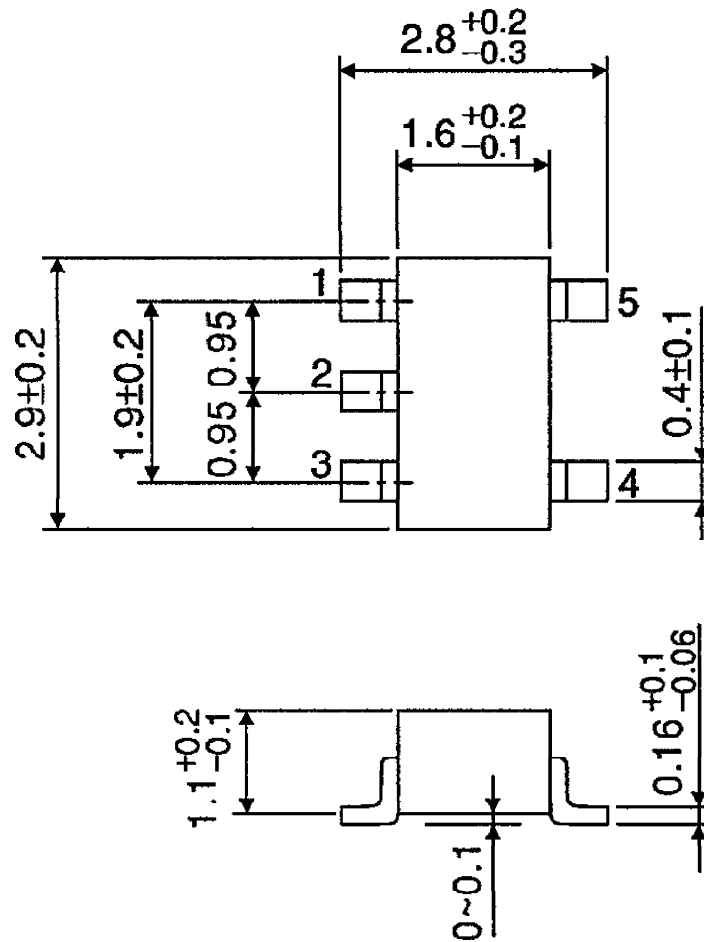


LOGIC DIAGRAM



OUTLINE DRAWING
SSOP5-P-0.95

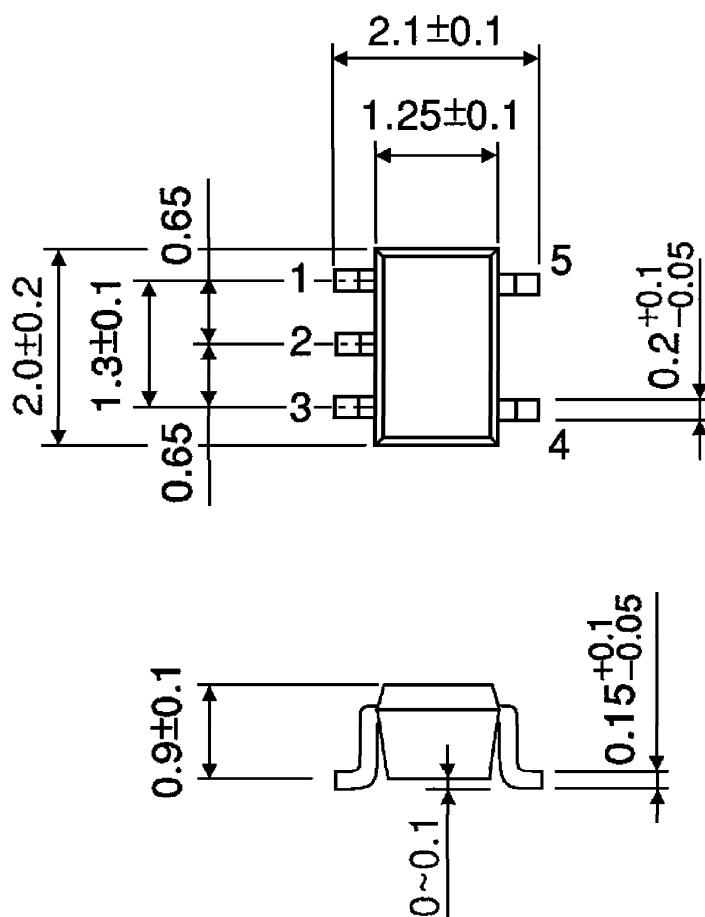
Unit : mm



Weight : 0.016 g (Typ.)

OUTLINE DRAWING
SSOP5-P-0.65A

Unit : mm



Weight : 0.006 g (Typ.)